

An AUTONOMOUS Institution

**Question Paper Code:** 

EC301ES

ACE-R20

## Semester Supplementary Examination II B. Tech- I Semester- SEPTEMBER-2022 ANALOG AND DIGITAL ELECTRONICS (COMMON TO CSE,IT)

Time: 3 Hours

Max. Marks: 70

	1.16
H. T. No	
11. 1. NO	

Answer any 5 Questions out of 8 Questions from the following M=Marks

Q.No	M=Marks		
1. a)			
b)			
ی ا	reactions with anyone of the example.		
2. a)	Compare the characteristics of DN innetically 15 1. 7		
	Tunnel diode, Zener Diode and Tunnel diode.		
b)	Explain the operation of Full Wave Rectifier with necessary waveforms.		
3. a)	Explain thermal run away and thermal stability.		
b)	Compare the performance of BJT as an amplifier in CE, CB, CC configuration	7	
4. a)		7	
b)	Explain Emitter follower with necessary diagrams	7	
UJ	Explain about multistage Common Emitter amplifier	/	
5. a)	Why we call FET as a Voltage Controlled Device.	7	
b)	Explain the NAND and in its investment of the NAND and in its investment of the NAND and in its investment of the NAND and invest	7	
6. a)	Explain the NAND gate circuit using DTL logic family	7	
o. aj	Obtain the compliment of the following Boolean expressions  i) A'B+A'BCI+A'BCD+A'BCIDIB		
	ii) ABEF+ABE'F'+A'B'FF	7	
b)	Minimize the following expression using K, man and Li		
	$(A,B,C,D) = \sum_{m=0}^{\infty} (0,1,2,9,11) + d(8,10,14,15).$	7	
7. a)	Derive sum and carry for Full Adder and draw the logic diagram with basic gates	/	
		7	
b)	Realize the function $f(A,B,C,D) = \Sigma m (1,4,6,10,14) + d(0,8,11,15)$ using 8:1 MUX.	,	
		7	
8. a)	Design the logic for SR flip flop using JK flip flop		
b)	Explain in detail about Random Access Memory	7	
	Titoess Memory	7	